

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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Site Map

HOME, Products > Opto Electronics > Optical Sensors > Transmission Type Photointerrupters > RPI-151

Photointerrupter Double Mold Type

ICs **Discrete** Semiconductors **Opto Electronics**

RPI-151 NEW

Data Sheet

Optical Sensors

Notes on mounting

Soldering conditions

ROHM Internet Direct

Print out Part No. explanation

■ FAQ

Shopping

2008.07.23 Industry's thinnest! 4 **Direction Detection** Sensor RPI-1040!

LED Displays

<u>LEDs</u>

Laser Diodes

Optical Sensors

Transmission type Photointerrupters

Reflective type Photosensors

Infrared Light Emitting Diodes

Phototransistors 4 Direction Detector

IrDA Infrared Communication Modules

Remote Control Receiver

Passive Components

Modules (Sub Systems)



[Product description]

ROHM's opetical sensors serve as eyes to monitor changes of any motions, and comply with customers' day-to-day diversifying requests.

Features

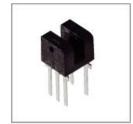
- ·Gap width1.5mm
- ·2-phase Output type

Product specifications

Absolute maximum ratings (Tc=25°C)							
Rated parameters	Standard value	Conditions					
Input(LED)							
Forward current I _F (mA)	50						
Reverse voltage V _R (V)	5						
Power dissipation P _D (mW)	70						
Collector-Emitter voltage V _{CEO} (V)	30						
Output(Photo-toransistor)							
Emitter-Collector voltage V _{ECO} (V)	4.5						
Collector current I _C (mA)	30						
Power dissipation P _C (mW)	80						
Temperature Characteristics							
Operating temperature Topr(°C)	-25 to 85						
Storage temperature Tstg(°C)	-30 to 85						

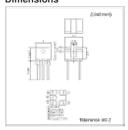
Electro-optical characteristics (Ta=25°C)					
Parameters	Value	Conditions			
Input Characteristics					
Input Characteristics Forward voltage V _F (V)	1.20	I _F =10mA			
Input Characteristics Reverse current I _R (µA)	10	V _R =10V			
Output Characteristics					
Output Characteristics Dark current-Max. ICEO(µA)	0.5	V _{CE} =10V			
Output Characteristics Peak sensitivity wavelength λP(nm)	800				
Transfer Characteristics					
Transfer Characteristics Collector current-Max. IC(mA)	0.25	V _{CE} =5V,I _F =5mA			
Transfer Characteristics Collector-Emitter saturation voltage-Max. VCE(sat) (V)	0.4	I _F =10mA,I _C =0.1mA			
Transfer Characteristics Response time tr⋅tf(μs)	10	$V_{CC} = 5V, I_F = 5mA, R_L = 100\Omega$			
Infrared Light Emitting Diode					
Infrared Light Emitting Diode Cut-	-	I _F =50mA			

Outline



2-phase Output Type

Dimensions



* Click to enlarge.



■ Inquiries concerning our products

Contact us

■ What is a Optical Sensors?

■ RoHS directive compliance

1					
off frequency F _C		* Non-coherent Infrared light emitting diode used.			
Infrared Light Emitting Diode Peak light emitting wavelength λP(nm)	950	I _F =50mA * Non-coherent Infrared light emitting diode used.			
Phototransistor					
Phototransistor Response time tr·tf(μs)		V _{CC} =5V,I _F =1mA,R _L =100Ω * This product is not designed to be protected against electromagnetic wave.			
Phototransistor Maximum sensitivity wavelength λP(nm)	800	-			

^{*}The contents described here are just outline for introduction.

Please obtain the specification sheets from us for thorough check before use.

Status Product						
Part No.	Status *1	RoHS	Packing style	Package quantity	Samples *2	Sales
RPI-151	Active	Yes	Plastic bag	1000	Purchase	Inquiry

^{*1} Active: Production or current type Preparation: Preliminary type Preview: Development type

Others

Please check the details on "Product List" for Others.

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^{*2} Available only as free rank.